

v05.1211

HMC824LP6CE

FRACTIONAL-N PLL WITH INTEGRATED VCO, 780 - 870 MHz

Features

- RF Bandwidth: 780 to 870 MHz
- Ultra Low Phase Noise -110 dBc/Hz in Band Typ.
- Figure of Merit (FOM) -227 dBc
- < 180 fs RMS Jitter

• 24-bit Step Size, Resolution 3 Hz typ

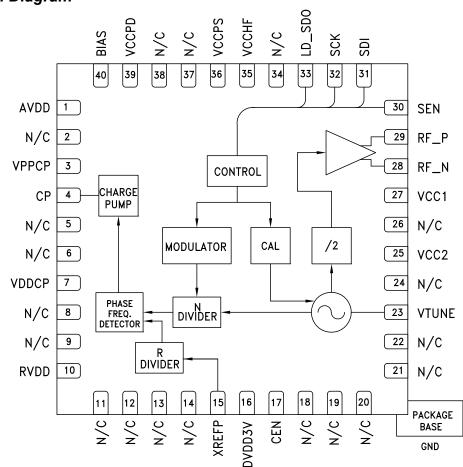
- Exact Frequency Mode
- Built-in Digital Self Test
- 40 Lead 6x6mm SMT Package: 36mm²

Typical Applications

- Cellular/4G Infrastructure
- Repeaters and Femtocells
- Communications Test Equipment
- CATV Equipment

Functional Diagram

- Phased Array Applications
- DDS Replacement
- Very High Data Rate Radios



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FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 780 - 870 MHz

General Description

The HMC824LP6CE is a fully functioned Fractional-N Phase-Locked-Loop (PLL) with an Integrated Voltage Controlled Oscillator (VCO). The PLL consists of an integrated low noise VCO with divide-by-2 output, an autocalibration subsystem for low voltage VCO tuning, a very low noise digital Phase Detector (PD), a precision controlled charge pump, a low noise reference path divider and a fractional divider.

The fractional PLL features an advanced delta-sigma modulator design that allows both ultra-fine step sizes and low spurious products. The phase detector (PD) features cycle slip prevention (CSP) technology to allow faster frequency hopping times. Ultra low in-close phase noise and low spurious also allows wider loop bandwidths for faster frequency hopping and low micro-phonics.

For theory of operation and register map refer to the "PLLs with Integrated VCOs - RF VCOs Operating Guide". To view the Operating Guide, please visit www.hittite.com and choose HMC824LP6CE from the "Search by Part Number" pull down menu.

Electrical Specifications, $T_A = +25^{\circ}$ C VPPCP, VDDCP, VCC1, VCC2 = 5V ±4%; RVDD, AVDD, DVDD3V, VCCPD, VCCHF, VCCPS = 3.3V ±6% GNDCP = GNDLS = Ground Paddle = 0V

Parameter	Condition	Min.	Тур.	Max.	Units
RF Output Characteristics					
VCO Frequency at PLL Input		1560		1740	MHz
RF Output Frequency at f _{VCO} /2		780		870	MHz
RF Output Power at f _{VCO} /2		11	14	16.5	dBm
VCO Tuning Sensitivity	Measured at 2 GHz, 2V		15		MHz/V
VCO Supply Pushing	Measured at 2 GHz, 2V	-2		1.5	MHz/V
RF Output 2nd Harmonic			-25		dBc
RF Output 3rd Harmonic			-23		dBc
RF Output 4th Harmonic			-31		dBc
RF Divider Characteristics	· · · · · · · · · · · · · · · · · · ·				
19-Bit N-Divider Range (Integer)	Max = 2 ¹⁹ - 1	16		524,287	
19-Bit N-Divider Range (Fractional)	Fractional nominal divide ratio varies (-3 / +4) dynamically max	20		524,283	
REF Input Characteristics					
Max Ref Input Frequency	Synthesizer phase noise can degrade by about 5dB when operating with a reference frequency near the low end of this range.	10	50	200	MHz
Ref Input Range	AC Coupled	1.5	2	3.3	Vpp
Ref Input Capacitance				5	pF
14-Bit R-Divider Range		1		16,383	
Phase Detector (PD)	· · · · · ·				
PD Frequency Fractional Feedback Mode	[1]	0.1		100	MHz
PD Frequency Fractional Feedforward Mode (and Register 6 [17:16]= 10)		0.1		80	MHz
PD Frequency Integer Mode	[1]	0.1		125	MHz

Note 1: This maximum phase detector frequency can only be achieved if the minimum N value is respected. eg. In the case of fractional feedback mode, the maximum PFD rate = fvco/20 or 100MHz, whichever is less.

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FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 780 - 870 MHz

ROHSV EARTH FRIENDLY

Electrical Specifications (Continued)

Parameter	Condition	Min.	Тур.	Max.	Units
Charge Pump					
Max Output Current		0.2		2.54	mA
Charge Pump Gain Step Size (5-Bits)			20		μA
PD/Charge Pump SSB Phase Noise	50 MHz Ref, Input Referred				
1 kHz			-141		dBc/Hz
10 kHz	Add 1 dB for Fractional		-149		dBc/Hz
100 kHz	Add 3 dB for Fractional		-153		dBc/Hz
Logic Inputs					
VIH Input High Voltage		DVDD3V-0.4		DVDD3V	V
VIL Input Low Voltage		0		0.4	V
Logic Outputs		, ,			
VOH Output High Voltage		DVDD3V-0.4		DVDD3V	V
VOL Output Low Voltage		0		0.4	V
Power Supply Voltages		·			
Analog 3.3V Supplies	AVDD, VCCHF, VCCPS, VCCPD, RVDD	3.0	3.3	3.5	v
Digital Supply	DVDD3V	3.0	3.3	3.5	V
Analog 5V Supplies	VPPCP, VDDCP, VCC1, VCC2	4.8	5	5.2	V
Power Supply Currents					
+5V Analog Charge Pump	VPPCP, VDDCP		5.3		mA
+5V VCO Core and PLL Buffer	VCC2		56		mA
+5V VCO Divider and RF Buffer	VCC1		36		mA
+3.3V Analog	AVDD, VCCHF, VCCPS, VCCPD, RVDD		45		mA
+3.3V Digital	DVDD3V		6.5		mA
Power Down - Crystal Off	Reg 01h=0, Crystal Not Clocked		10		μΑ
Power Down - Crystal On, 100 MHz	Reg 01h=0, Crystal Clocked 100 MHz		10	200	μA
Power on Reset					
Typical Reset Voltage on DVDD			700		mV
Min DVDD Voltage for No Reset		1.5			V
Power on Reset Delay			250		μs
VCO Open Loop Phase Noise at fvco/2					
825 MHz Divide-by-2 Output	10 kHz Offset		-93		dBc/Hz
825 MHz Divide-by-2 Output	100 kHz Offset		-123		dBc/Hz
825 MHz Divide-by-2 Output	1 MHz Offset		-148		dBc/Hz
825 MHz Divide-by-2 Output	10 MHz Offset		-162		dBc/Hz
825 MHz Divide-by-2 Output	100 MHz Offset		-166		dBc/Hz
Closed Loop Phase Noise PLL + VCO at fv	co/2	· · · ·		1	1
Integer, 25 MHz PFD	1 kHz Offset		-112		dBc/Hz
Integer, 25 MHz PFD	10 kHz Offset		-116		dBc/Hz
Integer, 25 MHz PFD	100 kHz Offset		-118		dBc/Hz
Integer, 25 MHz PFD	1 MHz Offset		-146		dBc/Hz

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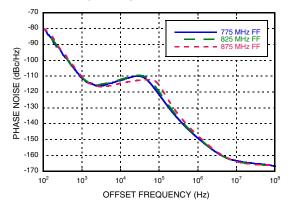
FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 780 - 870 MHz

Electrical Specifications (Continued)

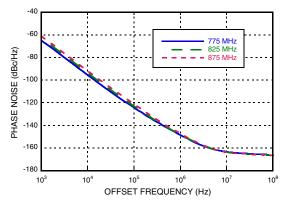
Parameter	Condition	Min.	Тур.	Max.	Units
Fractional, 25 MHz PFD	1 kHz Offset		-107		dBc/Hz
Fractional, 25 MHz PFD	10 kHz Offset		-113		dBc/Hz
Fractional, 25 MHz PFD	100 kHz Offset		-115		dBc/Hz
Figure of Merit	Normalized 1 Hz				
Integer Mode	Measured w/ 50 MHz PD at 30 kHz Offset		-229		dBc/Hz
Fractional Mode	Measured w/ 50 MHz PD at 30 kHz Offset		-227		dBc/Hz

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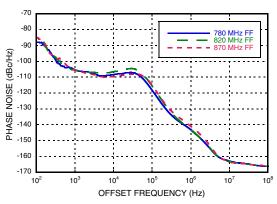
Closed Loop Integer Phase Noise



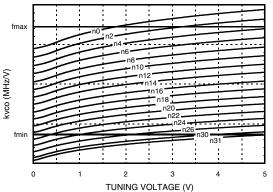
VCO/2 Free Running Phase Noise



Typical Closed Loop Fractional Phase Noise [1]



Typical VCO/2 Tuning Curves vs. Switch Position



[1] Fractional Mode, 50 MHz Crystal, R=1, ~80 kHz Loop BW, (Loop filter values: Contact factory for component values) 2mA Charge Pump, -385µA Offset.

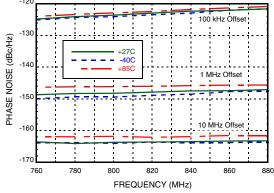
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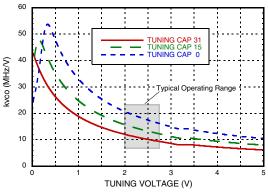
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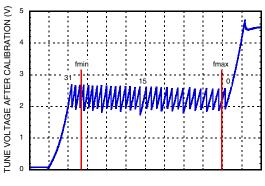


Typical VCO Sensitivity vs. Cap @ Fo Voltage



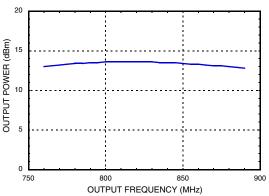
FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 780 - 870 MHz

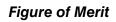
Typical VCO Tuning Voltage After Calibration

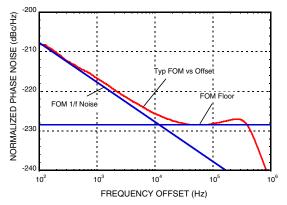


VCO FREQUENCY (MHz)

Typical Output Power - Narrow Band Match







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FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 780 - 870 MHz



Pin Descriptions

Pin Number	Function	Description	
1	AVDD	DC Power Supply for analog circuitry.	
2, 5, 6, 8, 9, 11 - 14, 18 - 22, 24, 26, 34, 37, 38	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	VPPCP	Power Supply for charge pump analog section	
4	CP	Charge Pump Output	
7	VDDCP	Power Supply for the charge pump digital section	
10	RVDD	Reference Supply	
15	XREFP	Reference Oscillator Input	
16	DVDD3V	DC Power Supply for Digital (CMOS) Circuitry	
17	CEN	Chip Enable. Connect to logic high for normal operation.	
23	VTUNE	VCO Varactor. Tuning Port Input.	
25	VCC2	VCO Analog Supply 2	
27	VCC1	VCO Analog Supply 1	
28	RF_N	VCO Divide by 2 RF Positive Output	
29	RF_P	VCO Divide by 2 RF Negative Output	
30	SEN	PLL Serial Port Enable (CMOS) Logic Input	
31	SDI	PLL Serial Port Data (CMOS) Logic Input	
32	SCK	PLL Serial Port Clock (CMOS) Logic Input	
33	LD_SDO	Lock Detect, or Serial Data, or General Purpose (CMOS) Logic Output (GPO)	
35	VCCHF	DC Power Supply for Analog Circuitry	
36	VCCPS	DC Power Supply for Analog Prescaler	
39	VCCPD	DC Power Supply for Phase Detector	
40	BIAS	External bypass decoupling for precision bias circuits. Note: 1.920V ±20mV reference voltage (BIAS) is generated internally and canno drive an external load. Must be measured with 10GΩ meter such as Agilent 34410 normal 10MΩ DVM will read erroneously.	

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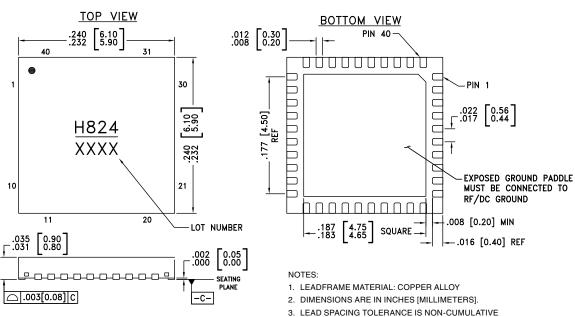
Absolute Maximum Ratings

-0.3V to +3.6V		
-0.3V to +5.8V		
-0.3V to +5.5V		
-40°C to +85°C		
-65°C to 125°C		
125 °C		
20 °C/W		
260°C		
40 sec		
Class 1B		

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 780 - 870 MHz

Outline Drawing



- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[1]
HMC824LP6CE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	<u>H824</u> XXXX

[1] 4-Digit lot number XXXX

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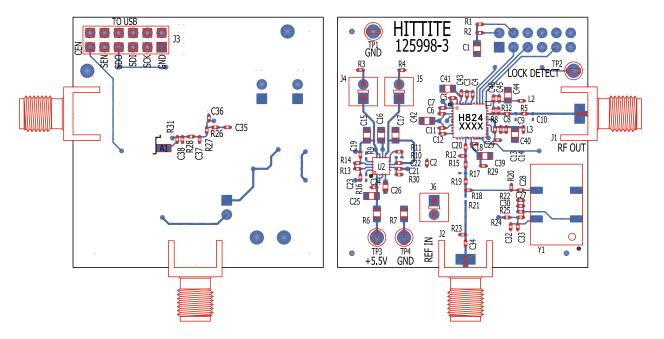


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Evaluation PCB



The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Evaluation PCB Schematic

To view this <u>Evaluation PCB Schematic</u> please visit www.hittite.com and choose HMC824LP6CE from the "Search by Part Number" pull down menu to view the product splash page.

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FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 780 - 870 MHz

List of Materials for Evaluation PCB 127828^[1]

Item	Description	
J1, J2	PCB Mount SMA RF Connector	
J3	Dual Row Terminal Strip	
J4 - J6	Connector Header	
C1, C15 - C17, C25	10 μF Capacitor, 0805 Pkg.	
C2, C3, C6, C7, C11, C12, C14, C18, C27, C43, C45	0.47 µF Capacitor, 0402 Pkg.	
C4, C13	22 pF Capacitor, 0402 Pkg.	
C5, C33	1000 pF Capacitor, 0402 Pkg.	
C8	2.2 pF Capacitor, 0402 Pkg.	
C19 - C24, C28, C30, C32, C34	0.1 µF Capacitor, 0402 Pkg.	
C26	1.0 µF Capacitor, 0603 Pkg.	
C29	47 pF Capacitor, 0402 Pkg.	
C35	3300 pF Capacitor, 0402 Pkg.	
C36	270 pF Capacitor, 0402 Pkg.	
C37, C38	68 pF Capacitor, 0402 Pkg.	
C39 - C42, C44	4.7 µF Tantalum Capacitor, 0805 Pkg	
C46	27 pF Capacitor, 0402 Pkg.	
R1, R2, R5, R11, R15, R18, R19, R21, R24	Zero Ohm Resistor, 0402 Pkg.	
R3, R4	1 Ohm Resistor, 0402 Pkg.	
R6, R7	0 Ohm Resistor, 0805 Pkg.	
R8	22 Ohm Resistor, 0402 Pkg.	
R12, R20, R29	51 Ohm Resistor, 0402 Pkg.	
R22, R25	20 kOhm Resistor, 0402 Pkg.	
R26 - R28	1k Ohm Resistor, 0402 Pkg.	
L1	12 nH Inductor, 0402 Pkg.	
L2, L3	47 nH Inductor, 0402 Pkg/	
TP3, TP4	Test Point PC Compact SMT	
U1	HMC824LP6CE PLL with Integrated VCO	
U2	HMC860LP3E Low Noise Quad Linear Regulator	
Y1	3.3V, 50 MHz VCXO Crystal Oscillator	
PCB ^[2]	125998 Evaluation Board	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR and FR4

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Notes:

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